

# YJ Planar Schottky Barrier Diode Die Specification

150V 10A, 88mil, Schottky barrier diode die based on silicon planar process

Part No.: PSB088H150SS-280A

## Main Products Characteristics

### Maximum Ratings

### Static Electrical Characteristics (Ta = 25°C)

$I_F = 10\text{ A}$

2%

### Device Schematics and Outline Drawing

Die Thickness \*